

PUMH11/ZLF Datasheet



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DiGi Electronics Part Number	PUMH11/ZLF-DG
Manufacturer	Nexperia USA Inc.
Manufacturer Product Number	PUMH11/ZLF
Description	TRANS PREBIAS
Detailed Description	Pre-Biased Bipolar Transistor (BJT) 2 NPN - Pre-Biased (Dual) 50V 100mA 230MHz 300mW Surface Mount 6-TSSOP



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:

PUMH11/ZLF

Series:

-

Transistor Type:

2 NPN - Pre-Biased (Dual)

Voltage - Collector Emitter Breakdown (Max):

50V

Resistor - Emitter Base (R2):

10kOhms

Vce Saturation (Max) @ Ib, Ic:

150mV @ 500µA, 10mA

Frequency - Transition:

230MHz

Grade:

Automotive

Mounting Type:

Surface Mount

Supplier Device Package:

6-TSSOP

Manufacturer:

Nexperia USA Inc.

Product Status:

Obsolete

Current - Collector (Ic) (Max):

100mA

Resistor - Base (R1):

10kOhms

DC Current Gain (hFE) (Min) @ Ic, Vce:

30 @ 5mA, 5V

Current - Collector Cutoff (Max):

1µA

Power - Max:

300mW

Qualification:

AEC-Q101

Package / Case:

6-TSSOP, SC-88, SOT-363

Base Product Number:

PUMH11

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

0000.00.0000

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

OBSOLETE



PUMH11

50 V, 100 mA NPN/NPN resistor-equipped double transistor;
R1 = 10 k Ω , R2 = 10 k Ω

1 October 2022

Product data sheet

1. General description

NPN/NPN double Resistor-Equipped Transistor (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

NPN/PNP complement: PUMD3

PNP/PNP complement: PUMB11

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

3. Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications

4. Quick reference data

Table 1. Quick reference data

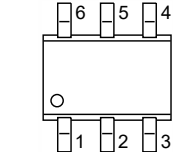
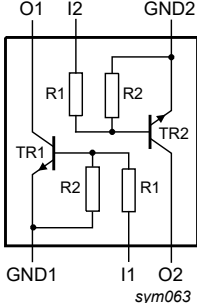
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Per transistor						
V _{CEO}	collector-emitter voltage	open base	-	-	50	V
I _O	output current		-	-	100	mA
R1	bias resistor 1 (input)		[1]	10	13	k Ω
R2/R1	bias resistor ratio		[1]	1	1.2	

[1] See "Section 11: Test information" for resistor calculation and test conditions.

50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1	 <p>TSSOP6 (SOT363)</p>	 <p><i>sym063</i></p>
2	I1	input (base) TR1		
3	O2	output (collector) TR2		
4	GND2	GND (emitter) TR2		
5	I2	input (base) TR2		
6	O1	output (collector) TR1		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PUMH11	TSSOP6	plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	SOT363

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PUMH11	H%1

[1] % = placeholder for manufacturing site code

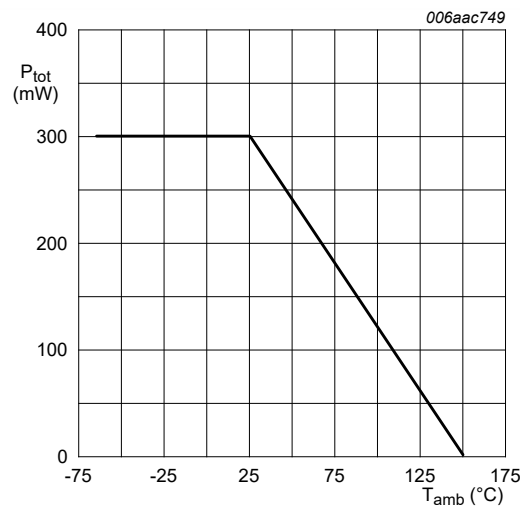
50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

8. Limiting values

Table 5. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transistor						
V _{CBO}	collector-base voltage	open emitter		-	50	V
V _{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	10	V
V _I	input voltage	positive		-	40	V
		negative		-	-10	V
I _O	output current			-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Per device						
P _{tot}	total power dissipation	T _{amb} = 25 °C	[1]	-	300	mW
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 μ m copper, tin-plated and standard footprint.



FR4 PCB, single-sided, 35 μ m copper, tin-plated and standard footprint

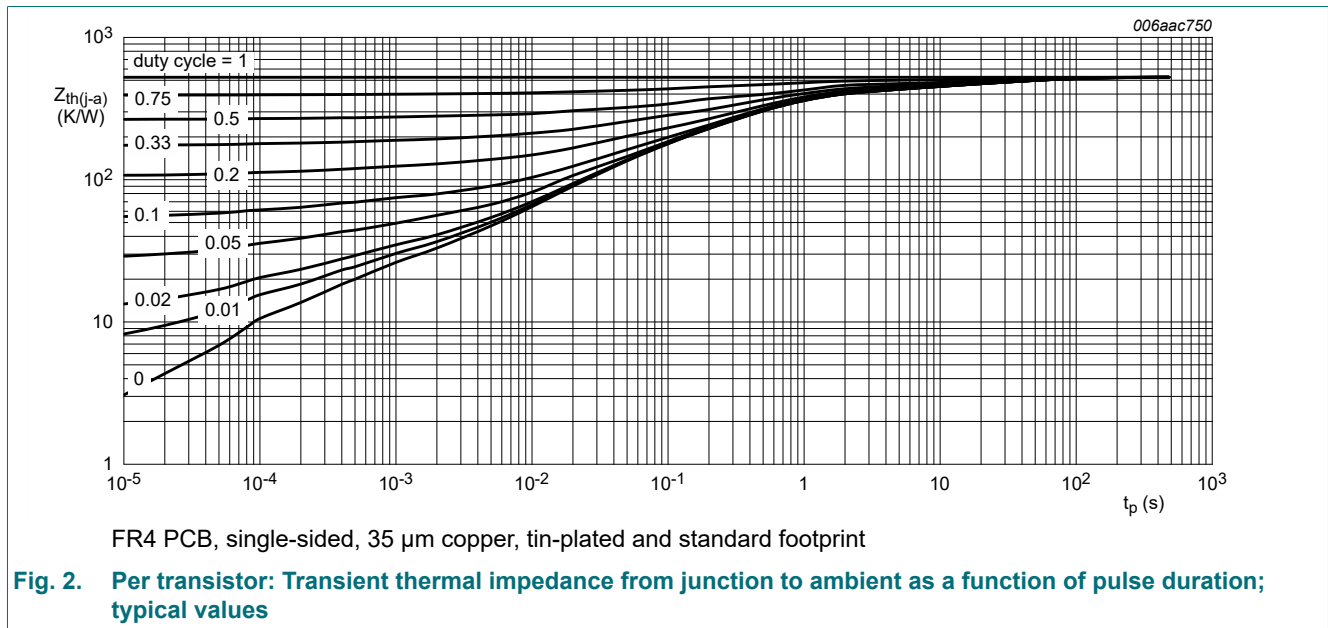
Fig. 1. Per device: Power derating curve

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W

[1] Device mounted on an FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint.



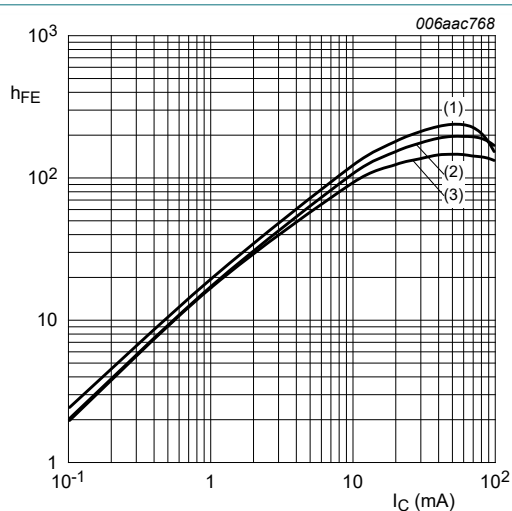
10. Characteristics

Table 7. Characteristics
 $T_{amb} = 25\text{ °C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
Per transistor							
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100\text{ }\mu\text{A}$; $I_E = 0\text{ A}$; $T_{amb} = 25\text{ °C}$	50	-	-	V	
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 2\text{ mA}$; $I_B = 0\text{ A}$; $T_{amb} = 25\text{ °C}$	50	-	-	V	
I_{CBO}	collector-base cut-off current	$V_{CB} = 50\text{ V}$; $I_E = 0\text{ A}$	-	-	100	nA	
I_{CEO}	collector-emitter cut-off current	$V_{CE} = 30\text{ V}$; $I_B = 0\text{ A}$	-	-	1	μA	
		$V_{CE} = 30\text{ V}$; $I_B = 0\text{ A}$; $T_J = 150\text{ °C}$	-	-	5	μA	
I_{EBO}	emitter-base cut-off current	$V_{EB} = 5\text{ V}$; $I_C = 0\text{ A}$	-	-	400	μA	
h_{FE}	DC current gain	$V_{CE} = 5\text{ V}$; $I_C = 5\text{ mA}$	30	-	-		
V_{CEsat}	collector-emitter saturation voltage	$I_C = 10\text{ mA}$; $I_B = 0.5\text{ mA}$	-	-	150	mV	
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5\text{ V}$; $I_C = 100\text{ }\mu\text{A}$	-	1.1	0.8	V	
$V_{I(on)}$	on-state input voltage	$V_{CE} = 0.3\text{ V}$; $I_C = 10\text{ mA}$	2.5	1.8	-	V	
R1	bias resistor 1 (input)		[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	
C_c	collector capacitance	$V_{CB} = 10\text{ V}$; $I_E = 0\text{ A}$; $i_e = 0\text{ A}$; $f = 1\text{ MHz}$	-	-	2.5	pF	
f_T	transition frequency	$V_{CE} = 5\text{ V}$; $I_C = 10\text{ mA}$; $f = 100\text{ MHz}$	[2]	-	230	-	MHz

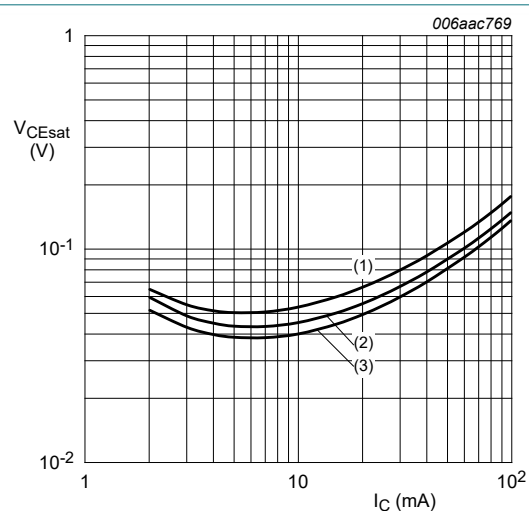
[1] See "Section 11: Test information" for resistor calculation and test conditions.

[2] Characteristics of built-in transistor



$V_{CE} = 5\text{ V}$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -40\text{ °C}$

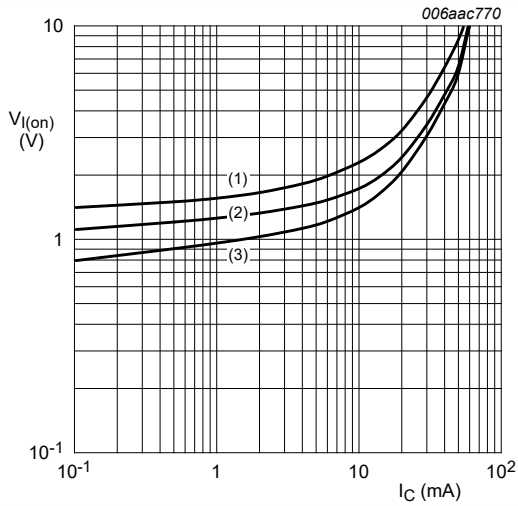
Fig. 3. DC current gain as a function of collector current; typical values



$I_C/I_B = 20$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -40\text{ °C}$

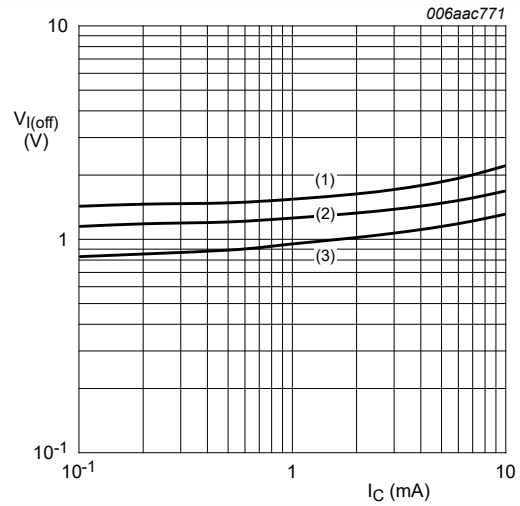
Fig. 4. Collector-emitter saturation voltage as a function of collector current; typical values

50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 10 kΩ, R2 = 10 kΩ



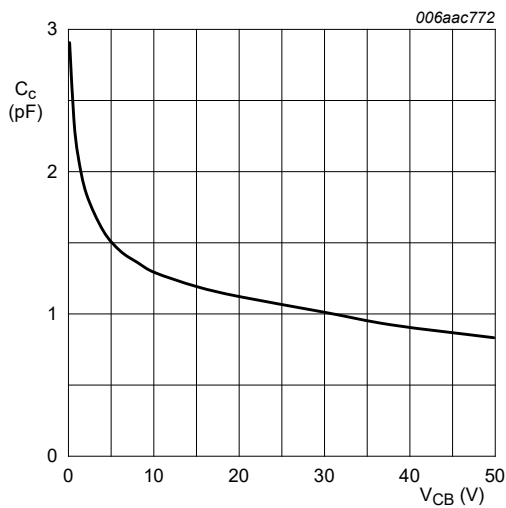
$V_{CE} = 0.3 \text{ V}$
 (1) $T_{amb} = -40 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = 100 \text{ }^\circ\text{C}$

Fig. 5. On-state input voltage as a function of collector current; typical values



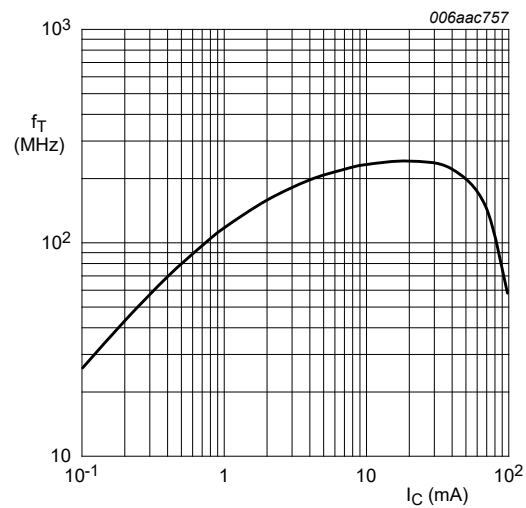
$V_{CE} = 5 \text{ V}$
 (1) $T_{amb} = -40 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = 100 \text{ }^\circ\text{C}$

Fig. 6. Off-state input voltage as a function of collector current; typical values



$f = 1 \text{ MHz}$
 $T_{amb} = 25 \text{ }^\circ\text{C}$

Fig. 7. Collector capacitance as a function of collector-base voltage; typical values



$f = 100 \text{ MHz}$
 $T_{amb} = 25 \text{ }^\circ\text{C}$
 $V_{CE} = 5 \text{ V}$

Fig. 8. Transition frequency as a function of collector current; typical values of built-in transistor

50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 10 kΩ, R2 = 10 kΩ

11. Test information

Resistor calculation

- Calculation of bias resistor 1 (R1)

$$R_1 = \frac{V(I_2) - V(I_1)}{I_2 - I_1}$$

- Calculation of bias resistor ratio (R2/R1)

$$\frac{R_2}{R_1} = \frac{V(I_4) - V(I_3)}{R_1 \cdot (I_4 - I_3)} - 1$$

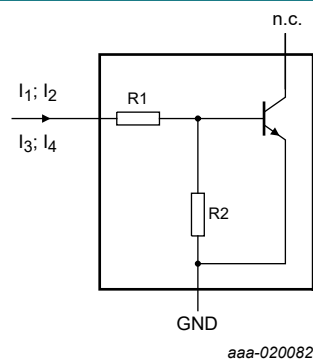


Fig. 9. NPN transistor: Resistor test circuit

Resistor test conditions

Table 8. Resistor test conditions

PUMH11	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I ₁	I ₂	I ₃	I ₄
TR1 (NPN)	10	10	350 μA	450 μA	-350 μA	-450 μA
TR2 (NPN)	10	10	350 μA	450 μA	-350 μA	-450 μA

12. Package outline

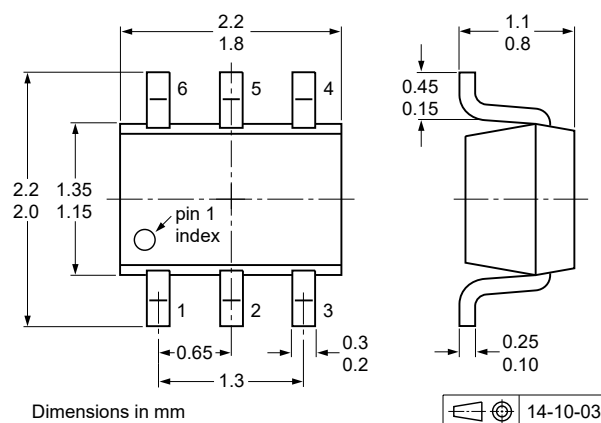


Fig. 10. Package outline TSSOP6 (SOT363)

13. Soldering

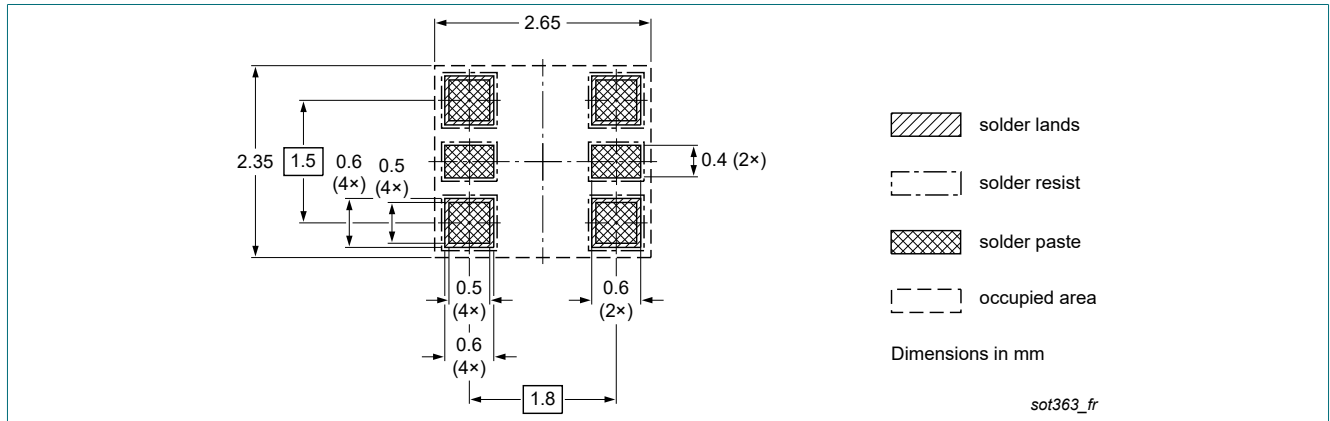


Fig. 11. Reflow soldering footprint for TSSOP6 (SOT363)

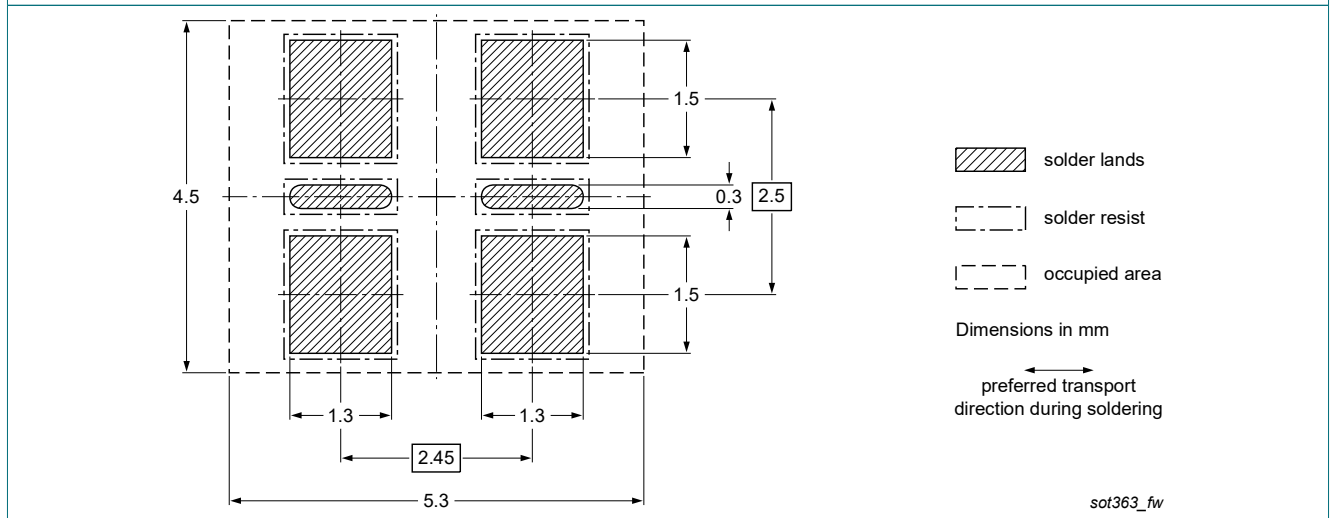


Fig. 12. Wave soldering footprint for TSSOP6 (SOT363)

50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 10 kΩ, R2 = 10 kΩ

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PUMH11 v.7	20221001	Product data sheet	-	PEMH11_PUMH11 v.6
Modifications:	<ul style="list-style-type: none"> The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Family data sheet reduced to single type data sheet. Product changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s). Packing information is removed. 			
PEMH11_PUMH11 v.6	20111129	Product data sheet	-	PEMH11_PUMH11 v.5
PEMH11_PUMH11 v.5	20031020	Product data sheet	-	PUMH11 v.4 PEMH11 v.1
PUMH11 v.4	19990413	Product specification	-	-
PEMH11 v.1	20011022	Preliminary specification	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

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